

Features

- · Trench Power LV MOSFET technology
- High Dense Cell Design For Extremely Low R_{DS(ON)}
- · Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- · Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

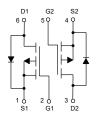
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Maximum Thermal Resistance: 89°C/W Junction to Ambient^(Note 2)

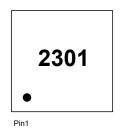
Parameter	Symbol	Rating	Unit		
Drain-Source Voltage		V _{DS}	-20	V	
Gate-Source Volltage		V _{GS}	±10	V	
Continuous Drain Current	T _A =25°C	- I _D	-3.8	^	
	T _A =70°C		-3	Α	
Pulsed Drain Current (Note3)		I _{DM}	-15.2	Α	
Total Power Dissipation ^(Note4)		P _D	1.4	W	

Note

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of R θ JA is measured with the device mounted on 1in2 FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

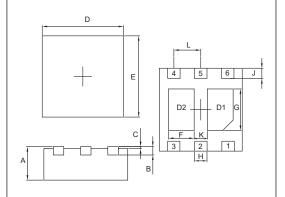
Internal Structure and Marking Code





P-Channel MOSFET

DFN2020-6L



	DIMENSIONS				
DIM	INC	HES	MM		NOTE
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.030	0.034	0.750	0.850	
В	0.008		0.200		TYP.
С	0.000	0.002	0.000	0.050	
D	0.077	0.081	1.950	2.050	
E	0.077	0.081	1.950	2.050	
F	0.017	0.027	0.440	0.690	
G	0.033	0.043	0.840	1.090	
Н	0.010	0.014	0.250	0.350	
J	0.007	0.015	0.175	0.375	
K	0.010	0.014	0.250	0.350	
L	0.026		0.650		TYP.



Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics							
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250μA	-20			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±8V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0V			-1	μA	
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-0.5	-0.7	-0.9	V	
Drain-Source On-Resistance		V _{GS} =-4.5V, I _D =-1.9A	44 55		55		
	R _{DS(on)}	V _{GS} =-2.5V, I _D =-1.9A		59	75	mΩ	
Gate Resistance	R_g	f=1MHz, Open drain		14		Ω	
Diode Characteristics							
Diode Forward Voltage	Is				-3.8	Α	
Continuous Body Diode Current	V _{SD}	V _{GS} =0V, I _S =-1.9A			-1.2	V	
Reverse Recovery Chrage	t _{rr}	I _F =-1.9A, dI _F /dt=100A/μs		27		ns	
Reverse Recovery Time	Q _{rr}	1.57, αιρτάτ 1007 γμο		12		nC	
Dynamic Characteristics			•				
Input Capacitance	C _{iss}			492			
Output Capacitance	C _{oss}	V_{DS} =-6V, V_{GS} =0V,f=1MHz		83		pF	
Reverse Transfer Capacitance	C _{rss}			70		1	
Total Gate Charge	Qg			5.8			
Gate-Source Charge	Q _{gs}	V_{DS} =-6V, V_{GS} =-4.5V, I_{D} =-2.8A		0.8		nC	
Gate-Drain Charge	Q_{gd}			1.2			
Turn-On Delay Time	t _{d(on)}			8			
Turn-On Rise Time	t _r	V _{GS} =-4.5V, V _{DD} =-6V,		8		no	
Turn-Off Delay Time	t _{d(off)}	I_D =-1A, R_G =6 Ω		54		ns	
Turn-Off Fall Time	t _f			21			



Curve Characteristics

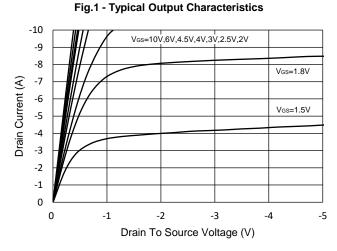


Fig.2 - Transfer Characteristic

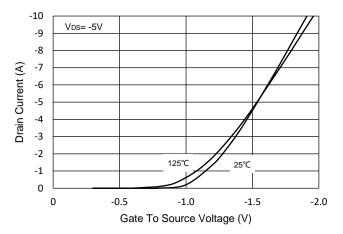


Fig.3 - $R_{DS(ON)}$ - V_{GS}

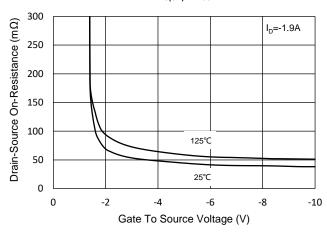


Fig.4 - $R_{DS(ON)}$ - I_D

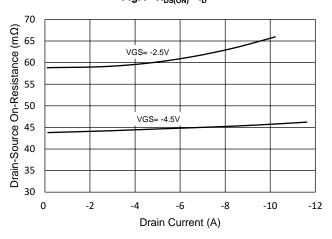


Fig.5 - Capacitance Characteristics

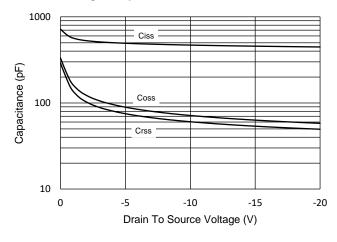
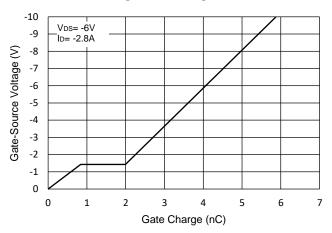
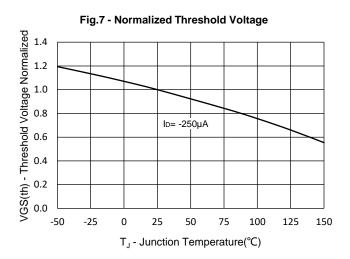


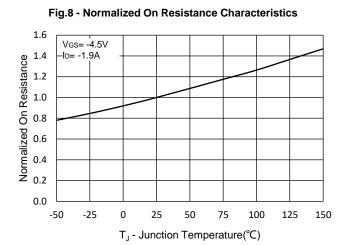
Fig.6 - Gate Charge

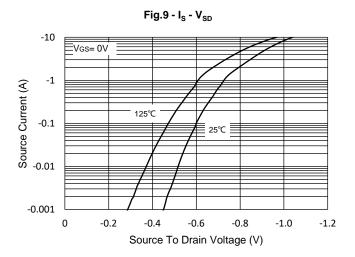


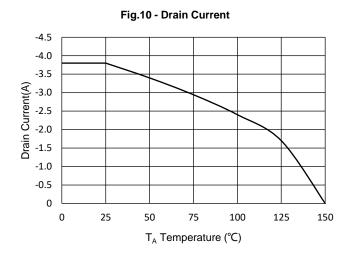


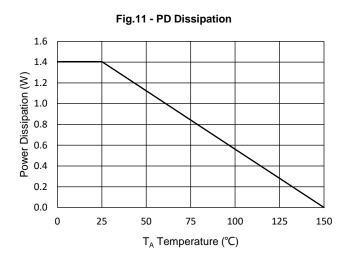
Curve Characteristics





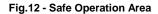








Curve Characteristics



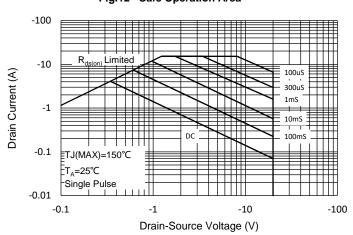
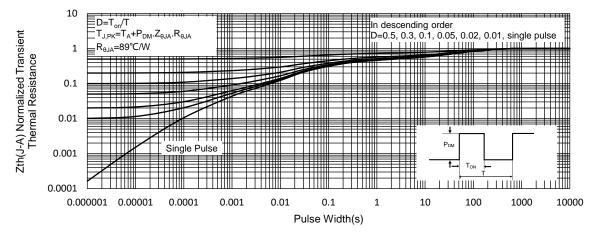


Fig.13 - Normalized Transient Thermal Impedance





Ordering Information

Device	Packing	
Part Number-TP	Tape&Reel:3Kpcs/Reel	

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